onsemi

NPN Transistor, 100 V, 3.0 A, Low V_{CE(sat)} NSS1C301ET4G

onsemi's e²PowerEdge family of low $V_{CE(sat)}$ transistors are surface mount devices featuring ultra low saturation voltage ($V_{CE(sat)}$) and high current gain capability. These are designed for use in low voltage, high speed switching applications where affordable efficient energy control is important.

Typical applications are DC–DC converters and power management in portable and battery powered products such as cellular and cordless phones, PDAs, computers, printers, digital cameras and MP3 players. Other applications are low voltage motor controls in mass storage products such as disc drives and tape drives. In the automotive industry they can be used in air bag deployment and in the instrument cluster. The high current gain allows e²PowerEdge devices to be driven directly from PMU's control outputs, and the Linear Gain (Beta) makes them ideal components in analog amplifiers.

Features

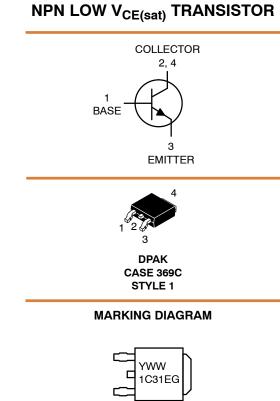
- Complement to NSS1C300ET4G
- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

MAXIMUM RATINGS $(1_A = 25^{\circ}C)$						
Rating	Symbol	Max	Unit			
Collector-Base Voltage	V _{CBO}	140	Vdc			
Collector-Emitter Voltage	V _{CEO}	100	Vdc			
Emitter-Base Voltage	V _{EB}	6.0	Vdc			
Collector Current – Continuous	Ι _C	3.0	Adc			
Collector Current – Peak	I _{CM}	6.0	Adc			
Base Current	Ι _Β	0.5	Adc			
Total Power Dissipation @ T _C = 25°C Derate above 25°C	P _D	33 0.26	W W/°C			
Total Power Dissipation (Note 1) @ T _A = 25°C Derate above 25°C	P _D	2.1 0.017	W W/°C			
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +150	°C			

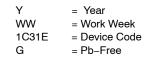
MAXIMUM RATINGS $(T_A = 25^{\circ}C)$

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. These ratings are applicable when surface mounted on the minimum pad sizes recommended.



100 VOLTS, 3.0 AMPS 12.5 WATTS



ORDERING INFORMATION

Device	Package	Shipping [†]
NSS1C301ET4G	DPAK (Pb-Free)	2500/ Tape & Reel
NSV1C301ET4G	DPAK (Pb–Free)	2500/ Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

NSS1C301ET4G

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	3.8	°C/W
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	59.5	°C/W

2. These ratings are applicable when surface mounted on the minimum pad sizes recommended.

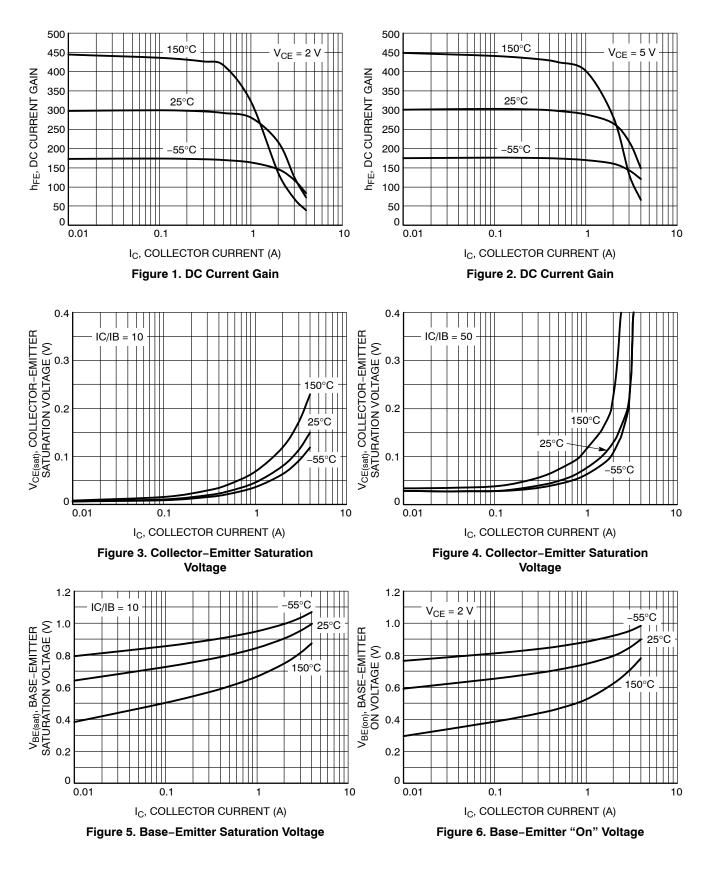
ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Мах	Unit
OFF CHARACTERISTICS	• • • •				•
Collector – Emitter Breakdown Voltage ($I_C = 10 \text{ mA}, I_B = 0$)	V _{(BR)CEO}	100	_	_	V
Collector – Base Breakdown Voltage $(I_{C} = 0.1 \text{ mA}, I_{E} = 0)$	V _{(BR)CBO}	140	-	_	V
Emitter – Base Breakdown Voltage ($I_E = 0.1 \text{ mA}, I_C = 0$)	V _{(BR)EBO}	6.0	_	-	V
Collector Cutoff Current (V _{CB} = 140 V, I _E = 0)	I _{CBO}	_	-	0.1	μΑ
Emitter Cutoff Current (V _{EB} = 6.0 V)	I _{EBO}	_	-	0.1	μΑ
ON CHARACTERISTICS					
DC Current Gain (Note 3) ($I_C = 0.1 A$, $V_{CE} = 2.0 V$) ($I_C = 0.5 A$, $V_{CE} = 2.0 V$) ($I_C = 1.0 A$, $V_{CE} = 2.0 V$) ($I_C = 3.0 A$, $V_{CE} = 2.0 V$)	h _{FE}	200 200 120 80		_ _ 360 _	_
Collector – Emitter Saturation Voltage (Note 3) ($I_C = 0.1 A$, $I_B = 10 mA$) ($I_C = 1.0 A$, $I_B = 0.100 A$) ($I_C = 2.0 A$, $I_B = 0.200 A$) ($I_C = 3.0 A$, $I_B = 0.300 A$)	V _{CE(sat)}	- - -	0.015 0.045 0.080 0.115	0.050 0.090 0.150 0.250	V
Base – Emitter Saturation Voltage (Note 3) $(I_C = 1.0 \text{ A}, I_B = 0.1 \text{ A})$	V _{BE(sat)}	-	-	1.0	V
Base – Emitter Turn–on Voltage (Note 3) (I _C = 1.0 A, V _{CE} = 2.0 V)	V _{BE(on)}	_	-	0.90	V
Cutoff Frequency (I _C = 500 mA, V _{CE} = 10 V, f = 100 MHz)	f _T	_	120	-	MHz
Input Capacitance (V _{EB} = 5.0 V, f = 1.0 MHz)	Cibo	_	360	-	pF
Output Capacitance (V _{CB} = 10 V, f = 1.0 MHz)	Cobo	_	30	-	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 3. Pulsed Condition: Pulse Width = $300 \ \mu s$, Duty Cycle $\leq 2\%$.

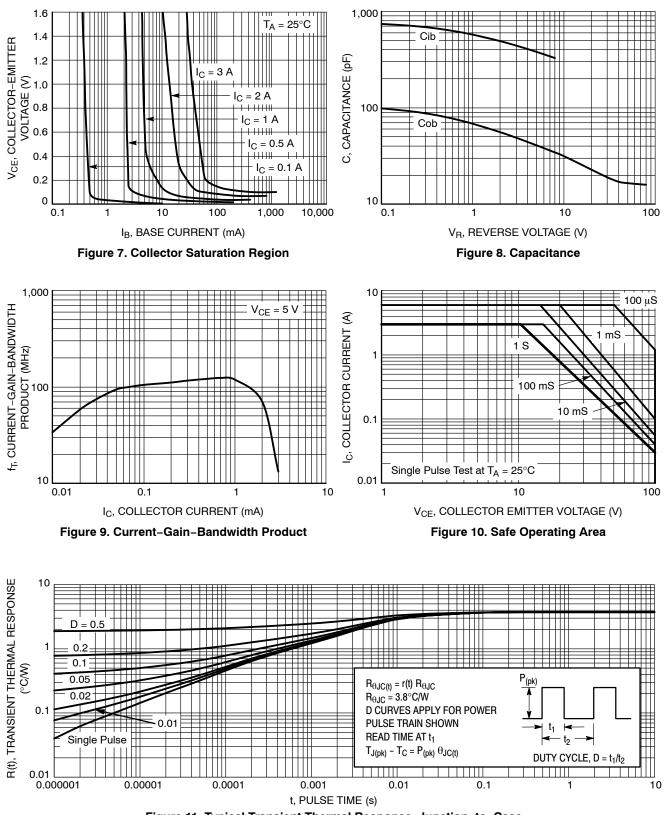
NSS1C301ET4G

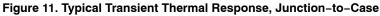
TYPICAL CHARACTERISTICS



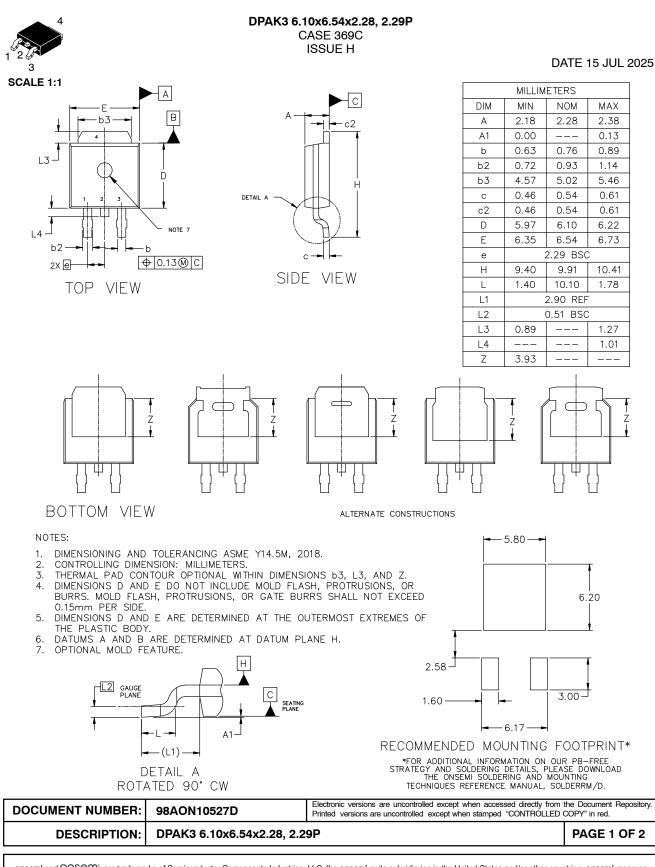
NSS1C301ET4G

TYPICAL CHARACTERISTICS





onsemi

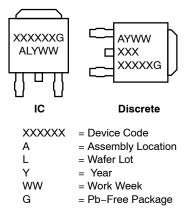


onsemi and ONSEMI are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

DPAK3 6.10x6.54x2.28, 2.29P CASE 369C ISSUE H

DATE 15 JUL 2025

GENERIC MARKING DIAGRAM*



*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

STYLE 1: PIN 1. BASE 2. COLLE 3. EMITTI 4. COLLE	ER 3. SOL	IN 2. CATI IRCE 3. ANO	HODE 2. ANODE DE 3. GATE	STYLE 5: PIN 1. GATE 2. ANODE 3. CATHODE 4. ANODE
STYLE 6:	STYLE 7:	3. ANODE	STYLE 9:	STYLE 10:
PIN 1. MT1	PIN 1. GATE		PIN 1. ANODE	PIN 1. CATHODE
2. MT2	2. COLLECTOR		2. CATHODE	2. ANODE
3. GATE	3. EMITTER		3. RESISTOR ADJUST	3. CATHODE
4. MT2	4. COLLECTOR		4. CATHODE	4. ANODE

DOCUMENT NUMBER:	98AON10527D	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.		
DESCRIPTION:	DPAK3 6.10x6.54x2.28, 2.29P		PAGE 2 OF 2	

onsemi and ONSEMI are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent_Marking.pdf</u>. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or indental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification. Buyer shall indemnify and hold onsemi and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs,

ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

Technical Library: www.onsemi.com/design/resources/technical-documentation onsemi Website: www.onsemi.com

ONLINE SUPPORT: <u>www.onsemi.com/support</u> For additional information, please contact your local Sales Representative at <u>www.onsemi.com/support/sales</u>